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Claims

Having described the invention, the following is claimed:

1	1. A surface acoustic wave device including a transducer electrode
2	formed on a substrate, the electrode having a plurality of layers, and at least one of the
3	layers being metal and another of the layers being a material for providing a hardening
4	effect to the metal layer.
1	2 A surface acoustic wave device as set forth in claim 1, wherein the

- 2 material is a metal and oxygen compound.
- 1 3. A surface acoustic wave device as set forth in claim 2, wherein the metal and oxygen compound includes aluminum.
 - 4. A surface acoustic wave device as set forth in claim 3, wherein the metal and oxygen compound is aluminum oxide.
 - 5. A surface acoustic wave device as set forth in claim 1, wherein the metal of the material includes aluminum.
 - 6. A surface acoustic wave device as set forth in claim 1, wherein the substrate is planar, each of the layers having a portion extending parallel to the substrate, the parallel extending portions being vertically stacked relative to the substrate, at least some of the layers also having portions extending transversely to the substrate, and the transverse extending portions being laterally stacked relative to the substrate.
- 7. A surface acoustic wave device as set forth in claim 6, wherein the second layer, of hardening material, has a portion extending laterally about the first layer, of metal, for preventing migration of the metal.

1	8. A surface acoustic wave device as set forth in claim 6, wherein the			
2	transverse portions do not extend onto the substrate beyond the electrode.			
1	9. A surface acoustic wave devices as set forth in claim 6, wherein the			
2	material is a metal and oxygen compound.			
1	10. A surface acoustic wave device as set forth in claim 9, wherein the			
2	metal and oxygen compound includes aluminum.			
1	11. A surface acoustic wave device as set forth in claim 10, wherein the			
2	metal and oxygen compound is aluminum oxide.			
1	12. A surface acoustic wave device as set forth in claim 6, wherein the			
2	metal of the material includes aluminum.			
1	13. A surface acoustic wave device as set forth in claim 1, wherein the			
2	transducer electrode is electrically connected to a metal component that permits			
3	electrical connection of the surface acoustic wave device to an electrical device			
4	external to the surface acoustic wave device, the electrode having a metal portion of a			
5	first metallization, and the component being of a second, different metallization.			
1	14. A surface acoustic wave device as set forth in claim 13, wherein the			
2	component includes a one of a bus bar and a bond pad.			

15. A surface acoustic wave device as set forth in claim 13, wherein the first metallization includes the metal portion of the electrode being made of a first metal, and the second metallization includes the component being made of a second, different metal.

1	16.	A surface acoustic wave device as set forth in claim 13, wherein the			
2	first metallization includes the metal portion of the electrode having a first thickness,				
3	and the second metallization includes the component having a second, different				
4	thickness.				
1	17.	A surface acoustic wave device including a transducer electrode			
2	formed on a substrate, the electrode having a plurality of layers, and at least one of the				
3	layers being r	metal and another of the layers being a metal and oxygen compound.			
1	18.	A surface acoustic wave device as set forth in claim 17, wherein the			
2	metal and oxy	ygen compound includes aluminum.			
1	19.	A surface acoustic wave device as set forth in claim 18, wherein the			
2	metal and oxy	ygen compound is aluminum oxide.			
1	20.	A method of making a surface acoustic wave device, the method			
2 :	including the	steps of:			
3		providing a substrate; and			
4		creating a transducer electrode having a plurality of layers on the			
5	substrate, inc	luding creating a metal layer and creating a layer of a material that			
6	provides a ha	rdening effect to the metal layer.			
1	21.	A method of making a surface acoustic wave device as set forth in			
2	claim 20, who	erein the step of creating a layer of a material includes creating the layer			
3	of material as	a metal and oxygen compound layer.			
1	22.	A method of making a surface acoustic wave device as set forth in			
2	claim 20, who	erein the step of creating a transducer electrode includes metal lift-off			
3	processing.				

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- 1 23. A surface acoustic wave device including a transducer electrode 2 electrically connected to a metal component that permits electrical connection of the 3 surface acoustic wave device to an electrical device external to the surface acoustic 4 wave device, the electrode having a metal portion of a first metallization, and the 5 component being of a second, different metallization.
 - 24. A surface acoustic wave device as set forth in claim 23, wherein the component includes one of a bus bar and a bond pad.
 - 25. A surface acoustic wave device as set forth in claim 23, wherein the first metallization includes the metal portion of the electrode being made of a first metal, and the second metallization includes the component being made of a second, different metal.
 - 26. A surface acoustic wave device as set forth in claim 23, wherein the first metallization includes the metal portion of the electrode having a first thickness, and the second metallization includes the component having a second, different thickness.
 - 27. A surface acoustic wave device as set forth in claim 23, wherein the electrode has a plurality of layers, and at least one of one of the layers being metal and another of the layers being a material for providing a hardening effect to the metal layer.
 - 28. A surface acoustic wave device as set forth in claim 27, wherein the material is a metal and oxygen compound.
 - 29. A surface acoustic wave device as set forth in claim 28, wherein the metal and oxygen compound includes aluminum.

- 30. A surface acoustic wave device as set forth in claim 29, wherein the metal and oxygen compound is aluminum oxide.
- 31. A surface acoustic wave device as set forth in claim 27, wherein the metal of the material includes aluminum.
- 32. A surface acoustic wave device as set forth in claim 27, wherein the substrate is planar, each of the layers having a portion extending parallel to the substrate, the parallel extending portions being vertically stacked relative to the substrate, at least some of the layers also having portions extending transverse to the substrate, and the transverse extending portions being laterally stacked relative to the substrate.
 - 33. A surface acoustic wave device as set forth in claim 32, wherein the second layer, of hardening material, has a portion extending laterally about the first layer, of metal, for preventing migration of the metal.
- 34. A surface acoustic wave device as set forth in claim 32, wherein the transverse portions do not extend onto the substrate beyond the electrode.
- 1 35. A surface acoustic wave device as set forth in claim 32, wherein the material is a metal and oxygen compound.
- 1 36. A surface acoustic wave device as set forth in claim 35, wherein the 2 metal and oxygen compound includes aluminum.
 - 37. A surface acoustic wave device as set forth in claim 36, wherein the metal and oxygen compound is aluminum oxide.
- 1 38. A surface acoustic wave device as set forth in claim 32, wherein the metal of the material includes aluminum.

	39. A surface acoustic wave device including a transducer electrode		
electrically connected to a component that permits electrical connection of the surface			
	acoustic wave device to an electrical device external to the surface acoustic wave		
	device, the electrode having a metal portion made of a first metal, and the component		
	being made of a second, different metal.		

- 40. A surface acoustic wave device including a transducer electrode electrically connected to a component that permits electrical connection of the surface acoustic wave device to an electrical device external to the surface acoustic wave device, the electrode having a metal portion of a first thickness, and the component being metal of a second, different thickness.
- 41. A method of making a surface acoustic wave device, the method including the steps of:

making a transducer electrode, including making the electrode to have a metal portion of a first metallization; and

making a metal component, electrically connected to the electrode, that permits electrical connection of the surface acoustic wave device to an electrical device external to the surface acoustic wave device, including making the component of a second, different metallization.

42. A method of making a surface acoustic wave device as set forth in claim 41, wherein the steps of making a transducer electrode and making a metal component include metal lift-off processing.